Vishay General Semiconductor

## **Dual Common-Cathode Schottky Rectifier**



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PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2 x 10 A				
V <sub>RRM</sub>	50 V, 60 V				
I <sub>FSM</sub>	150 A				
$V_F$ at $I_F$ = 10 A	0.570 V				
T <sub>J</sub> max.	150 °C				

### FEATURES

- Guardring for overvoltage protection
- Lower power losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- High frequency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### **TYPICAL APPLICATIONS**

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, OR-ing diodes, DC/DC converters or polarity protection application.

#### **MECHANICAL DATA**

Case: TO-220AB

Molding compound meets UL 94V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

<b>MAXIMUM RATINGS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER		SYMBOL	MI2050C	MI2060C	UNIT	
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	50	60	V	
Maximum average forward rectified current (Fig.1)	total device	<b>I</b> =44.6	20		A	
	per diode	I <sub>F(AV)</sub>	10			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I <sub>FSM</sub>	150		А	
Peak repetitive reverse current per leg at $t_p$ = 2 µs, 1 kHz per diode		I <sub>RRM</sub>	0.5		А	
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10 000		V/µs	
Operating junction temperature range		TJ	- 65 to +150		°C	
Storage temperature range		T <sub>STG</sub>	- 65 to +175		°C	

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ROHS COMPLIANT



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<b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25$ °C unless otherwise noted)							
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNIT	
Maximum instantaneous forward voltage per diode	V <sub>F</sub> <sup>(1)</sup>	I <sub>F</sub> = 5 A	T <sub>J</sub> = 25 °C	0.554	-	V	
		I <sub>F</sub> = 10 A	T <sub>J</sub> = 125 °C	0.649	0.74		
		I <sub>F</sub> = 5 A	T <sub>J</sub> = 25 °C	0.484	-		
		I <sub>F</sub> = 10 A	T <sub>J</sub> = 125 °C	0.570	0.62		
Reverse current per diode	I <sub>R</sub> <sup>(2)</sup>	rated V <sub>R</sub>	T <sub>J</sub> = 25 °C	15	150	μA	
			T <sub>J</sub> = 100 °C	10.8	25	mA	
Typical junction capacitance	CJ	4.0 V, 1 MHz		300	-	pF	

#### Notes

<sup>(1)</sup> Pulse test: 300 µs pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: Pulse width  $\leq$  40 ms

<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	SYMBOL	MI2050C	MI2060C	UNIT		
Typical thermal resistance per diode	$R_{ ext{ heta}JC}$	2.	°C/W			

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g) PACKAGE CODE		BASE QUANTITY	DELIVERY MODE	
TO-262AA	MI2060C-E3/4W	1.456	4W	50/tube	Tube	

#### RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

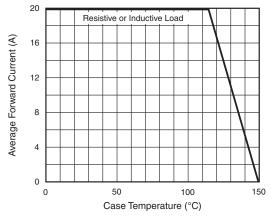


Fig. 1 - Forward Current Derating Curve

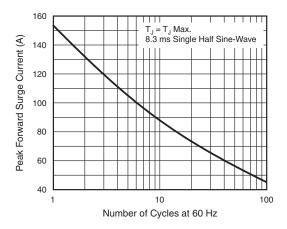


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge pCurrent Per Diode



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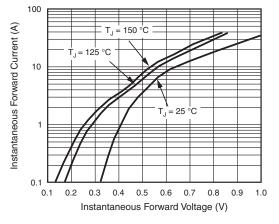


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

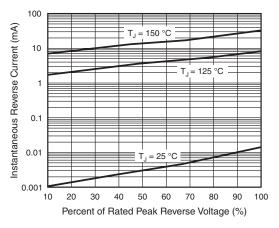


Fig. 4 - Typical Reverse Characteristics Per Diode

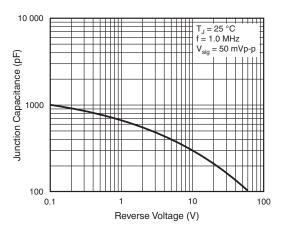


Fig. 5 - Typical Junction Capacitance Per Diode

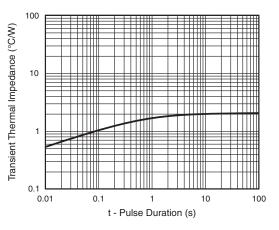
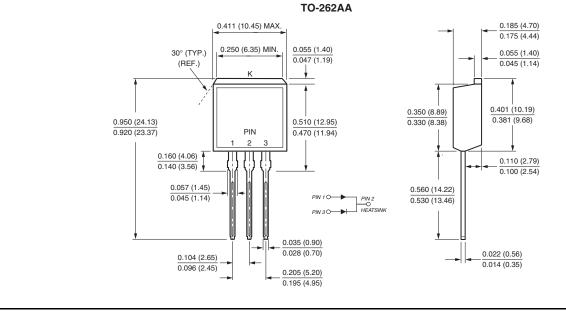


Fig. 6 - Typical Transient Thermal Impedance Per Diode



### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

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For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



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